

Effect of disorder on the far-infrared conductivity and on the microwave conductivity of two-band superconductors

Božidar Mitrović

Department of Physics, Brock University, St.Catharines, Ontario, Canada L2S 3A1

E-mail: mitrovic@brocku.ca

Abstract. We consider the far-infrared and the microwave conductivities of a two-band superconductor with non-magnetic impurities. The strong coupling expressions for the frequency and temperature dependent conductivity of a two-band superconductor are developed assuming isotropic bands and interactions. Our numerical results obtained using realistic interaction parameters for MgB_2 are compared with experiments on this compound. We find that the available experimental results for the far-infrared conductivity of MgB_2 are consistent with multi-band superconductivity in the presence of a sufficiently strong interband impurity scattering. On the other hand, our numerical results for the microwave conductivity in the superconducting state indicate that the experimental results obtained on samples with the highest transition temperature T_c are consistent with a low interband impurity scattering rate but depend sensitively on the ratio of the total scattering rates in the two bands. For the π -band scattering rate γ_π not greater than the σ -band scattering rate γ_σ there is a single, broad, low-temperature (at about $0.5T_c$) coherence peak in the microwave conductivity. For $\gamma_\pi/\gamma_\sigma=4-7$ a high-temperature (at about $0.9T_c$) coherence peak is dominant, but there is also a low-temperature peak/shoulder resulting from the contribution of the π -band carriers to the microwave conductivity. For $\gamma_\pi/\gamma_\sigma \gg 1$ only the high-temperature coherence peak should be observable.

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1. Introduction

The far-infrared spectroscopy of superconducting MgB_2 seems to indicate the presence of a single gap Δ with the ratio $2\Delta/k_B T_c$ significantly below the BCS value of 3.53 (see a recent review by Kuzmenko [1] and the references therein). In contrast to this finding, the angle-resolved photoemission spectroscopy [2, 3], the tunneling spectroscopy [4, 5, 6, 7, 8, 9, 10, 11, 12], the Raman spectroscopy [13, 14, 15, 16] and the heat capacity measurements [17, 18, 19, 20] on magnesium diboride have all established two distinct superconducting gaps Δ_σ and Δ_π in σ - and π -bands. Since the far-infrared measurements [21, 22] were performed on films with reduced superconducting transition temperature T_c , we investigate the possibility that the interband non-magnetic impurity scattering, which is known to reduce the transition temperature of multi-band superconductors [23, 24, 25, 26], is responsible for the observation of a single gap. Namely, Schopohl and Scharnberg [27] found that the interband impurity scattering produces a common low temperature gap Δ in both bands of a two-band superconductor such that the quasiparticle densities of states in each band vanish at energies below Δ in the low temperature limit, figure 1. In the limit of small interband impurity scattering rate, the common gap is just above the lower of the two gaps in the clean system (figure 1a). As the interband impurity scattering rate increases the common gap grows in size (figure 1b), but remains lower than the larger of the two gaps in the clean system, and for a sufficiently large interband impurity scattering rate the order parameters (the gap functions) in both bands become the same (the Anderson theorem [28]). The growth of the common gap with the interband impurity scattering rate is accompanied by progressive smearing of the peaks in the quasiparticle densities of states in the two bands, figure 1. Since the frequency (ν) dependent conductivity $\sigma(\nu)$ is a functional of both the normal and the anomalous quasiparticle densities of states, one would expect the frequency dependence of $\sigma(\nu)$ to be modified compared to what is predicted by a straightforward application of the Mattis-Bardeen theory [29] which uses the BCS form for the quasiparticle densities of states. In particular, terahertz time-domain measurements of Kaindl *et al.* on MgB_2 films [21] found that the real part of $\sigma(\nu)$ increased more slowly for ν just above twice the gap than what was predicted by the Mattis-Bardeen theory. This finding is significant since the BCS-type Mattis-Bardeen theory describes quite well the low frequency dependence of $\text{Re } \sigma(\nu)$ even for a strong coupling superconductor Pb (see figure 3 in [30]). We find that the observed $\sigma(\nu)$ of MgB_2 films [21] is consistent with multi-band superconductivity in this compound in the presence of a sufficiently strong interband impurity scattering.

The microwave conductivity of MgB_2 was measured in [31, 32, 33] with different results. In [31], the normalized real part of the conductivity at 17.9 GHz ($\nu=0.074$ meV) measured on the c -axis oriented MgB_2 films had a broad maximum at a temperature of about $0.6T_c$, instead of the usual coherence peak seen in the dirty limit just below the T_c [34]. The data of Lee *et al.* [32] obtained at 8.5 GHz ($\nu=0.035$ meV) on polycrystalline MgB_2 films with the T_c s of 39.3 K and 36.3 K showed rather sharp

coherence peaks at about $0.9T_c$. In addition, the results obtained on the film with the higher T_c showed a second, lower, peak at about $0.53T_c$ which appears to be sharper than the broad oval feature seen in [31] (see figures 3 and 4 in [32]). Upon ion-milling the second peak became more of a shoulder at about $0.6T_c$, the peak at $0.9T_c$ became broadened, but increased in size, and the T_c dropped from 39.4 K to 36.3 K. The results for the normalized microwave conductivity obtained in [33] at 19 GHz ($\nu=0.079$ meV) on MgB_2 and $\text{Mg}_{0.95}\text{Al}_{0.05}\text{B}_2$ pellets resembled more those found in [32]. The Al-doped sample displayed more pronounced shoulder at about $0.4T_c$ - $0.5T_c$ and a more pronounced coherence peak just below the T_c than the magnesium diboride sample. Here we also investigate theoretically the effect of impurity scattering on the temperature (T) dependence of the microwave conductivity $\text{Re}\sigma(\nu, T)$ of a two-band superconductor. We find that the shape of $\text{Re}\sigma(\nu, T)$ depends strongly on both the intraband and the interband impurity scattering rates.

The rest of the paper is organized as follows. In section 2 we write down the equations for the optical conductivity of each band which include explicitly and implicitly the intraband and the interband impurity scattering rates. Section 3 contains our results for $\sigma(\nu, T)$ obtained using realistic interaction parameters for MgB_2 and a comparison of experimental results [21] with our theoretical predictions. The same section also contains our results for the temperature dependence of the microwave conductivity and their comparison with experiments [31, 32, 33]. Section 4 contains a summary. In the Appendix we provide a connection between the main results of [35] which used the BCS treatment of the same problem at zero temperature and the present work.

2. Theory

The optical conductivity of a two-band superconductor with non-magnetic impurities was first considered by Sung and Wong [35]. They used the BCS treatment of the pairing interactions in two isotropic bands and included the s -wave impurity scattering in the self-consistent second Born approximation. The general expression for the zero temperature optical conductivity of a two-band superconductor with impurities was developed using the standard linear response theory in the conserving approximation [36]. Since the electron self-energies were obtained in the self-consistent second Born approximation, only the ladder impurity diagrams had to be considered in evaluating the current-current correlator $-\langle T_\tau(j_\alpha(\mathbf{q} = 0, -i\tau)j_\beta(\mathbf{q} = 0, 0)) \rangle$ [36]. However, the graphs where the interband scattering impurity lines cross the current vertex vanish because of the assumed isotropy of the bands and impurity scattering matrix elements [37]. As a result, the paramagnetic part of the electromagnetic response kernel is simply the sum of the contributions from individual bands. In terms of concrete quantitative predictions, they only pointed out that the absorption threshold should increase with increasing interband impurity scattering rate/impurity concentration, figure 1.

Here we generalize the results in [35] to include the strong-coupling effects because

it is known [24],[25],[26] that the weak-coupling BCS treatment of the effect of interband impurity scattering [23] badly overestimates the rate of suppression of T_c in MgB₂. Also, the BCS treatment requires an unphysical value of the Debye cutoff of 7.5 meV [32], while it is known that the superconductivity of MgB₂ is mainly driven by electron coupling to the optical B-B bond stretching modes at about 74 meV.

As in [35], we will make the assumption of isotropic bands and interactions (electron-phonon, screened Coulomb and electron-impurity). The assumed isotropy of the interaction parameters implies that there are no vertex corrections to current vertices in the current-current correlator $-\langle T_\tau(j_\alpha(\mathbf{q} = 0, -i\tau)j_\beta(\mathbf{q} = 0, 0)) \rangle$ [37] and, as in [35], the conductivity is simply the sum of conductivities of separate bands. The calculation of the $\mathbf{q} = 0$ conductivity $\sigma_n(\nu)$ of a band n in the superconducting state is performed in the standard way (see, for example, a pedagogical account in [38] and the references therein) and one finds the usual result [34, 38]

$$\begin{aligned} \sigma_n(\nu) = \frac{\omega_{pn}^2}{8\pi\nu} \left\{ \int_0^{+\infty} d\omega \tanh \frac{\omega}{2T} \frac{1 - N_n(\omega)N_n(\omega + \nu) - M_n(\omega)M_n(\omega + \nu)}{-iE_n(\omega) - iE_n(\omega + \nu)} \right. \\ + \int_0^{+\infty} d\omega \tanh \frac{\omega + \nu}{2T} \frac{1 - N_n^*(\omega)N_n^*(\omega + \nu) - M_n^*(\omega)M_n^*(\omega + \nu)}{-iE_n^*(\omega) - iE_n^*(\omega + \nu)} \\ + \int_0^{+\infty} d\omega \left(\tanh \frac{\omega + \nu}{2T} - \tanh \frac{\omega}{2T} \right) \frac{1 + N_n^*(\omega)N_n(\omega + \nu) + M_n^*(\omega)M_n(\omega + \nu)}{iE_n^*(\omega) - iE_n(\omega + \nu)} \\ + \int_{-\nu}^0 d\omega \tanh \frac{\omega + \nu}{2T} \left[\frac{1 - N_n^*(\omega)N_n^*(\omega + \nu) - M_n^*(\omega)M_n^*(\omega + \nu)}{-iE_n^*(\omega) - iE_n^*(\omega + \nu)} \right. \\ \left. \left. + \frac{1 + N_n^*(\omega)N_n(\omega + \nu) + M_n^*(\omega)M_n(\omega + \nu)}{iE_n^*(\omega) - iE_n(\omega + \nu)} \right] \right\}, \end{aligned} \quad (1)$$

where $n, m = \sigma, \pi$. Here, ω_{pn}^2 is the square of the plasma frequency in the band n , and the real parts of

$$N_n(\omega) = \frac{\omega}{\sqrt{\omega^2 - \Delta_n^2(\omega)}} \quad (2)$$

and

$$M_n(\omega) = \frac{\Delta_n(\omega)}{\sqrt{\omega^2 - \Delta_n^2(\omega)}} \quad (3)$$

are normalized normal and anomalous quasiparticle densities of states, respectively, in the band n . The quasiparticle energy in the band n , $E_n(\omega)$, appearing in the denominators in (1) is defined by

$$E_n(\omega) = Z_n(\omega) \sqrt{\omega^2 - \Delta_n^2(\omega)}, \quad (4)$$

where $Z_n(\omega)$ is the total renormalization function for the band n which includes the intraband and the interband electron-phonon interaction and impurity scattering, and $\Delta_n(\omega)$ is the total gap function (renormalized pairing self-energy [36]) in the band n which depends on the intraband and the interband electron-phonon interaction and

screened Coulomb interaction and only on the interband impurity scattering (see below). In (2- 4) and throughout this paper we take the branch of the square root with positive imaginary part and the energy ω is assumed to have infinitesimal positive imaginary part.

The gap functions $\Delta_n(\omega)$ and the renormalization functions $Z_n(\omega)$ are obtained by solving the Eliashberg equations at finite temperature on the real axis [39]

$$\phi_n(\omega) = \phi_n^0(\omega) + i \sum_m \frac{1}{2\tau_{nm}} \frac{\Delta_m(\omega)}{\sqrt{\omega^2 - \Delta_m^2(\omega)}} , \quad (5)$$

$$\begin{aligned} \phi_n^0(\omega) = \sum_m \int_0^{\omega_c} d\omega' \operatorname{Re} [M_m(\omega)] & \left[f(-\omega') K_{nm}^+(\omega, \omega') - f(\omega') K_{nm}^+(\omega, -\omega') \right. \\ & \left. - \mu_{nm}^*(\omega_c) \tanh \frac{\omega'}{2T} + \bar{K}_{nm}^+(\omega, \omega') - \bar{K}_{nm}^+(\omega, -\omega') \right] , \end{aligned} \quad (6)$$

$$Z_n(\omega) = Z_n^0(\omega) + i \sum_m \frac{1}{2\tau_{nm}} \frac{1}{\sqrt{\omega^2 - \Delta_m^2(\omega)}} , \quad (7)$$

$$\begin{aligned} Z_n^0(\omega) = 1 - \frac{1}{\omega} \sum_m \int_0^{+\infty} d\omega' \operatorname{Re} [N_m(\omega)] & \left[f(-\omega') K_{nm}^-(\omega, \omega') \right. \\ & \left. - f(\omega') K_{nm}^-(\omega, -\omega') + \bar{K}_{nm}^-(\omega, \omega') + \bar{K}_{nm}^-(\omega, -\omega') \right] . \end{aligned} \quad (8)$$

Equations (5-8) imply that the gap functions $\Delta_n(\omega) = \phi_n(\omega)/Z_n(\omega)$ are independent of the intraband impurity scattering rate $1/\tau_{nn}$, but are affected by the interband impurity scattering rate $1/\tau_{nm}$, $n \neq m$. The intraband and the interband electron-phonon coupling functions $\alpha^2 F_{nm}(\Omega)$ enter via the zero temperature kernels $K_{nm}^\pm(\omega, \omega')$ and the thermal phonon kernels $\bar{K}_{nm}^\pm(\omega, \omega')$ defined by

$$K_{nm}^\pm(\omega, \omega') = \int_0^{+\infty} d\Omega \alpha^2 F_{nm}(\Omega) \left[\frac{1}{\omega' + \omega + \Omega + i0^+} \pm \frac{1}{\omega' - \omega + \Omega - i0^+} \right] , \quad (9)$$

$$\bar{K}_{nm}^\pm(\omega, \omega') = \int_0^{+\infty} d\Omega \frac{\alpha^2 F_{nm}(\Omega)}{e^{\Omega/T} - 1} \left[\frac{1}{\omega' + \omega + \Omega + i0^+} \pm \frac{1}{\omega' - \omega + \Omega - i0^+} \right] . \quad (10)$$

The screened Coulomb interaction for the cutoff ω_c in the Eliashberg equations is described by the intraband and the interband Coulomb repulsion parameters $\mu_{nm}^*(\omega_c)$. The impurity scattering rates are defined by $\gamma_{nm} \equiv 1/\tau_{nm} = 2\pi n_{imp} N_{Fm} |V_{nm}|^2$, where n_{imp} is the concentration of impurities, N_{Fm} is the normal state electronic density of states per spin at the Fermi level in band m and V_{nm} is the Fermi surface averaged matrix element of the change in the lattice potential caused by an impurity between the states in the bands n and m .

In the single band case it is customary to make the dependence of the conductivity on the impurity scattering rate more explicit as it enters only the total renormalization

function [34]. The same can be done in multi-band case, while keeping in mind that the interband impurity scattering also enters implicitly through the gap function $\Delta_n(\omega)$, equations (1-4). To this end $Z_n(\omega)$ in (4) is replaced by (7) and one has

$$E_n(\omega) = Z_n^0(\omega) \sqrt{\omega^2 - \Delta_n^2(\omega)} + \frac{i}{2\tau_{nn}} + \frac{i}{2\tau_{nm}} \frac{\sqrt{\omega^2 - \Delta_n^2(\omega)}}{\sqrt{\omega^2 - \Delta_m^2(\omega)}} \quad (11)$$

$$= Z_n^0(\omega) \sqrt{\omega^2 - \Delta_n^2(\omega)} + \frac{i}{2\tau_{nn}} + \frac{i}{2\tau_{nm}} \frac{N_m(\omega)}{N_n(\omega)} \quad (12)$$

with $m \neq n$, and in the second line we have utilized the definition (2). We point out that in the limit of zero interband scattering $1/\tau_{nm}=0$, $m \neq n$, (12) is given by $E_n(\omega) = Z_n^0(\omega) \sqrt{\omega^2 - \Delta_n^2(\omega)} + i/2\tau_{nn}$ and (1) takes the usual single band form given in [34] (see equation (3) in [34]).

In the normal state $N_n(\omega)=1$, $M_n(\omega)=0$, $E_n(\omega) = Z_n^0(\omega)\omega$ and (1) reduces to

$$\sigma_n^N(\nu) = \frac{\omega_{pn}^2}{8\pi\nu} \left\{ \int_0^{+\infty} d\omega \left(\tanh \frac{\omega + \nu}{2T} - \tanh \frac{\omega}{2T} \right) \times \right. \\ \left. \frac{iZ_n^{0*}(\omega)\omega - iZ_n^0(\omega + \nu)(\omega + \nu) + 1/\tau_{nn} + 1/\tau_{nm}}{2} + \int_{-\nu}^0 d\omega \tanh \frac{\omega + \nu}{2T} \frac{iZ_n^{0*}(\omega)\omega - iZ_n^0(\omega + \nu)(\omega + \nu) + 1/\tau_{nn} + 1/\tau_{nm}}{2} \right\}, \quad (13)$$

with $m \neq n$, which is the standard result for the total impurity scattering rate $\gamma_n = 1/\tau_n = 1/\tau_{nn} + 1/\tau_{nm}$, $m \neq n$, in the band n . In (13) $Z_n^0(\omega)$ is obtained from (8) with $N_m(\omega)=1$.

In the Appendix we provide a translation of the notation used in [35] into the notation used in this work in order to facilitate comparison between our results and the BCS zero-temperature results of [35].

3. Numerical Results

In all of our numerical work we use four electron-phonon coupling functions $\alpha^2 F_{nm}(\Omega)$, $n, m = \sigma, \pi$, for MgB₂ calculated by Golubov *et al.* [40]. The corresponding electron-phonon coupling parameters $\lambda_{nm} = \text{Re } K_{nm}^+(0, 0)$, equation (9), are $\lambda_{\sigma\sigma} = 1.017$, $\lambda_{\sigma\pi} = 0.212$, $\lambda_{\pi\pi} = 0.446$ and $\lambda_{\pi\sigma} = 0.155$. The Coulomb repulsion parameters $\mu_{nm}^*(\omega_c)$ were determined in [24] based on the screened Coulomb interactions in MgB₂ calculated by Choi *et al.* [41] by fitting to the experimental T_c of the clean system. The solutions $\Delta_\sigma(\omega)$ and $\Delta_\pi(\omega)$ of (5-8) depend only on the band off-diagonal impurity scattering rates and since $\gamma_{\sigma\pi}/\gamma_{\pi\sigma} = N_{F\pi}/N_{F\sigma} = \lambda_{\sigma\pi}/\lambda_{\pi\sigma} = 1.37$, there is only one independent interband scattering parameter and we chose $\gamma_{\pi\sigma}$ as the independent parameter.

The contributions to the conductivity of the carriers in the two bands depend also on the intraband impurity scattering rates and on the plasma frequencies of the two bands and in the following we choose the values of $\gamma_{\sigma\sigma} = 1/\tau_{\sigma\sigma}$, $\gamma_{\pi\pi} = 1/\tau_{\pi\pi}$, $\omega_{p\sigma}$ and $\omega_{p\pi}$ according to a particular set of experiments, guided by the band structure calculations. However, it should be noted that there is no unique way of determining

even just two parameters $\gamma_{\sigma\sigma}$ and $\gamma_{\pi\pi}$ from the measured conductivity just above the T_c , assuming that the plasma frequencies are as given by the band structure calculations and that the interband scattering rate $\gamma_{\pi\sigma}$ can be deduced from the T_c of the film and the calculated T_c vs. $\gamma_{\pi\sigma}$ curve [24, 25, 26]. This uncertainty necessarily makes any detailed comparison with experiments difficult. Thus, we will focus on qualitative changes in the conductivities of the two bands brought about by the two-band superconductivity in MgB_2 in the presence of impurity scattering.

3.1. Frequency and temperature dependence of the far-infrared conductivity

In the experiments of Kaindl *et al.* on MgB_2 [21] the T_c of the 100 nm film used for the measurement of $\sigma(\nu)$ was 30.5 K. If one assumes that this reduction in the transition temperature from the maximum value of $T_{c0}=39.4$ K results solely from the interband impurity scattering (i. e. if one ignores any possible changes to the Fermi level densities of states $N_{F\sigma}$ and $N_{F\pi}$ and/or the electron-phonon coupling functions) one can deduce the value of the interband impurity scattering rate $\gamma_{\pi\sigma}$ from the T_c vs. $\gamma_{\pi\sigma}$ curve calculated in [24]. In this way we find $\gamma_{\pi\sigma}=5T_{c0}$, where T_{c0} is the transition temperature of the clean system. The corresponding normalized quasiparticle densities of states obtained from the solutions of (5-8) are shown in figure 1b. The measured real part of the normal state conductivity at 40 K was about $8 \times 10^5 \Omega^{-1} \text{m}^{-1}$ (see the inset in figure 2 in [21]). This value is mainly determined by the impurity scattering and one can deduce $\gamma_{\sigma\sigma}$ and $\gamma_{\pi\pi}$ by choosing appropriate values of $\omega_{p\sigma}$ and $\omega_{p\pi}$ and making an assumption about the ratio $\gamma_{\pi}/\gamma_{\sigma}$, where $\gamma_{\pi} = \gamma_{\pi\pi} + \gamma_{\pi\sigma}$ and $\gamma_{\sigma} = \gamma_{\sigma\sigma} + \gamma_{\sigma\pi}$. We chose $\omega_{p\pi}=5.89$ eV and $\omega_{p\sigma}=4.14$ eV calculated in [42] and assumed $\gamma_{\pi}/\gamma_{\sigma}=7$ as suggested by Kuzmenko [1], which resulted in $\gamma_{\pi}=2.6$ eV and $\gamma_{\sigma}=0.371$ eV. These choices do not affect the calculated $\text{Re } \sigma_n(\nu)/\text{Re } \sigma_n^N(\nu)$, $n = \sigma, \pi$ given by (1) and (13) but only $\text{Re } \sigma(\nu)/\text{Re } \sigma^N(\nu)$, with $\sigma(\nu) = \sigma_{\sigma}(\nu) + \sigma_{\pi}(\nu)$. In figure 2 we show our results for the normalized conductivities at several temperatures and the results obtained by using the single-gap Mattis-Bardeen theory [29] (dashed lines). With our interaction parameters described at the beginning of this section and $\gamma_{\pi\sigma}=5T_{c0}$ we obtained for the common low temperature gap, figure 1b, $\Delta=3.875$ meV. The transition temperature T_c was determined from the temperature dependence of the conductivity in the low frequency limit (see the next subsection) and we found $T_c=33.2$ K giving $2\Delta/k_B T_c = 2.7$ which is higher than the value found in [21] but still well below the BCS value of 3.53. The five temperatures for which we calculated the conductivities in figure 2 were chosen such that they correspond to the same values of T/T_c considered in [21] and they are $T=7$ K, 19 K, 26 K, 29 K and 32.75 K. The results of Mattis-Bardeen theory (dashed lines in figure 2) were obtained by taking $\Delta=3.875$ meV as the zero temperature gap and assuming that the temperature dependence of the gap is given by the BCS theory as calculated by Mühlischlegel [43].

The most important feature of our results in figure 2 is that both $\text{Re } \sigma_{\sigma}(\nu)/\text{Re } \sigma_{\sigma}^N(\nu)$ and $\text{Re } \sigma_{\pi}(\nu)/\text{Re } \sigma_{\pi}^N(\nu)$ increase more slowly above twice the gap than what is predicted by the Mattis-Bardeen theory, in particular at the lower

temperatures. The reduction in the rate of increase in the normalized real part of the conductivity compared to the prediction of the Mattis-Bardeen theory is more pronounced for the σ -band than for the π -band. The reduced rate of increase in $\text{Re } \sigma_n(\nu)/\text{Re } \sigma_n^N(\nu)$, $n = \sigma, \pi$ is related to the smearing of both the normal quasiparticle density of states $\text{Re } N_n(\omega)$, figure 1, and the anomalous quasiparticle density of states $M_n(\omega)$ by the interband impurity scattering. Note that for the interband impurity scattering rate $\gamma_{\pi\sigma}=5T_{c0}$, which was used to obtain the results in figure 2, $\text{Re } N_\sigma(\omega)$ is broadened more than $\text{Re } N_\pi(\omega)$, figure 1b, resulting in a slower increase of $\text{Re } \sigma_\sigma(\nu)/\text{Re } \sigma_\sigma^N(\nu)$ compared to $\text{Re } \sigma_\pi(\nu)/\text{Re } \sigma_\pi^N(\nu)$. Indeed, in figure 3 we show $\text{Re } \sigma_\pi(\nu)/\text{Re } \sigma_\pi^N(\nu)$ at a low temperature calculated for $\gamma_{\pi\sigma}=0.1T_{c0}$, together with the prediction of the Mattis-Bardeen theory. For such a small interband impurity scattering rate the smearing in $\text{Re } N_\pi(\omega)$ compared to the BCS result $\text{Re } (\omega/\sqrt{\omega^2 - \Delta^2})$ is quite small, figure 1a, and in this case the Mattis-Bardeen theory provides an excellent fit. We conclude that the observed [21] single gap and a slower rise in $\text{Re } \sigma(\nu)/\text{Re } \sigma^N(\nu)$ above twice the gap compared to the prediction of the Mattis-Bardeen theory are consistent with the multi-band superconductivity in MgB_2 in the presence of a sufficiently strong interband impurity scattering.

3.2. Temperature dependence of the microwave conductivity

In figure 4 we show the temperature dependence of the microwave conductivity at 8.5 GHz ($\nu=0.035$ meV) calculated from equation (1) using the values of $\omega_{p\sigma}$, $\omega_{p\pi}$ and γ_π/γ_σ suggested by Kuzmenko [1]: $\omega_{p\sigma}=4.14$ eV, $\omega_{p\pi}=4.72$ eV and $\gamma_\pi/\gamma_\sigma=7$. The value of γ_π was fitted to the microwave conductivity of $1.26 \times 10^7/\Omega\text{m}$ measured in [32] at the transition temperature of the film of MgB_2 with a higher T_c ($T_c=39.3$ K). We obtained $\gamma_\pi=152.6$ meV and for different choices of $\gamma_{\pi\sigma}$ in figure 4 the values of $\gamma_{\pi\pi}$ and $\gamma_{\sigma\sigma}$ were adjusted to keep $\gamma_\pi = \gamma_{\pi\pi} + \gamma_{\pi\sigma}$ and $\gamma_\sigma = \gamma_{\sigma\sigma} + \gamma_{\sigma\pi}$ fixed (note that $\gamma_{\sigma\pi}/\gamma_{\pi\sigma}=1.37$ is constant). In this way the same microwave conductivity at T_c is obtained for different values of the interband scattering rate.

The results in figure 4 are analogous to what was obtained previously by Mitrović and Samokhin [39] for the nuclear magnetic resonance (NMR) relaxation rate in two-band superconductors. This is because both the NMR relaxation rate and the microwave conductivity have the same coherence factors in the single band case. For no interband impurity scattering ($\gamma_{\pi\sigma}=0$) the microwave conductivity of the σ -band has the usual coherence peak at about $0.9T_c$, while the microwave conductivity of the π -band displays an unusual broad peak, first noted in [31] at about $0.4T_c$ - $0.5T_c$. The difference in temperatures of the two coherence peaks is a direct consequence of the difference in the energies at which the low temperature quasiparticle densities of states in the two bands have singularities, figure 1a. For finite interband impurity scattering, the transition temperature is reduced with increasing $\gamma_{\pi\sigma}$ and the size of the coherence peak in the σ -band contribution to the microwave conductivity is reduced for $\gamma_{\pi\sigma}$ up to about T_{c0} , figure 4a, as a result of the reduction and broadening of the peaks in $\text{Re } N_\sigma(\omega)$ and

$\text{Re } M_\sigma(\omega)$. Since the peaks in $\text{Re } N_\pi(\omega)$ and $\text{Re } M_\pi(\omega)$ are less smeared for low values of $\gamma_{\pi\sigma}$ than those in the σ -band, figure 1a, the effect of the interband impurity scattering on a broad π -band coherence peak is small for small $\gamma_{\pi\sigma}$. As $\gamma_{\pi\sigma}$ grows, $\text{Re } N_\pi(\omega)$ and $\text{Re } M_\pi(\omega)$ become more broadened and start approaching $\text{Re } N_\sigma(\omega)$ and $\text{Re } M_\sigma(\omega)$, figure 1b, as the difference in the gap functions in the two bands becomes smaller. The consequence of these changes in $N_\pi(\omega)$ and $M_\pi(\omega)$ is that the coherence peak in π -band contribution to the microwave conductivity starts moving closer to the T_c and the shape of $\text{Re } \sigma_\pi(T)$ for fixed ν in the microwave range starts resembling that of $\text{Re } \sigma_\sigma(T)$. In figure 5 we show the microwave conductivities calculated for parameters used in the previous subsection with $\gamma_{\pi\sigma}=5T_{c0}$. The shapes of $\text{Re } \sigma_\pi(T)$ and $\text{Re } \sigma_\sigma(T)$ are qualitatively the same since the peaks in the corresponding densities of states occur at similar energies, figure 1b. As pointed out in [39], in the limit of very large $\gamma_{\pi\sigma}$ (the Anderson limit [28]) the gap functions in the two bands become identical leading to identical normal and anomalous quasiparticle densities of states in both bands. This in turn would imply the usual temperature dependence of the microwave conductivity with the coherence peak at about $0.9T_c$, barring extremely strong electron-phonon coupling [38].

From figure 4 it is clear that the results of Jin *et al.* [31] with a broad coherence peak at about $0.6T_c$ could be obtained with a small interband scattering rate $\gamma_{\pi\sigma}$, which is consistent with a rather high $T_c=39.4$ K of their samples [44], and with γ_π less than or comparable to γ_σ . Indeed, in figure 6 we show a series of our results calculated with $\gamma_{\pi\sigma}=0.1T_{c0}$ and $\gamma_\pi=0.5\gamma_\sigma$ (figure 6a), $\gamma_\pi=\gamma_\sigma$ (figure 6b), $\gamma_\pi=2\gamma_\sigma$ (figure 6c), $\gamma_\pi=2.67\gamma_\sigma$ (figure 6d), $\gamma_\pi=4\gamma_\sigma$ (figure 6e) and $\gamma_\pi=6.67\gamma_\sigma$ (figure 6f). The dashed curves in figure 6 give the σ -band contributions to the microwave conductivity, dash-dotted curves give the π -band contributions to the microwave conductivity and the solid lines give the total microwave conductivity. We used $\omega_{p\pi}=5.89$ eV, $\omega_{p\sigma}=4.14$ eV [42] and the value of γ_π was fitted to the measured microwave conductivity at T_c of $1.37 \times 10^7/\Omega\text{m}$ [31] assuming $\text{Re } \sigma_\sigma(T_c) = \omega_{p\pi}^2/(4\pi\gamma_\pi) + \omega_{p\sigma}^2/(4\pi\gamma_\sigma)$. In this way we obtained $\gamma_\pi=42.5$ meV, 50.9 meV, 68.1 meV, 78.6 meV, 100.9 meV and 145.4 meV for figures 6a through 6f, respectively. Clearly, only the results in figures 6a and 6b are consistent with the experimental observation in [31]. The calculated microwave conductivity in figures 6e and 6f is consistent with the experimental findings in [32, 33], but rather sharp peaks at $0.53T_c$ and $0.9T_c$ observed in [32] on a film with the higher T_c (39.3 K) cannot be reproduced theoretically. We note that the shape of the calculated σ -band contribution to the microwave conductivity is quite similar to that of Nb [31, 34], which is not surprising since the σ -band electron phonon coupling parameter $\lambda_{\sigma\sigma}=1.017$ is comparable to that of Nb.

4. Summary

We have developed strong coupling expressions for the frequency and temperature dependent conductivity of a two-band superconductor which include the intraband

and the interband scattering by non-magnetic impurities, assuming isotropic bands and interactions. Our numerical calculations, using realistic interaction parameters for MgB₂, show that the experimental observations [21] of a single gap and a lower rate of increase in the far infrared conductivity above the absorption threshold, compared to the prediction of Mattis-Bardeen theory [29], are consistent with multi-band superconductivity in MgB₂ in the presence of a sufficiently strong disorder. The results for the microwave conductivity show that the intraband and the interband impurity scattering rates play the key role in determining its temperature dependence. The experimental results in [31, 32, 33], at least on the samples with nearly optimum transition temperatures, are consistent with a low interband impurity scattering rates and their precise shape seems to depend on the sample quality as reflected by the ratio γ_π/γ_σ of the impurity scattering rates in the two bands. For $\gamma_\pi/\gamma_\sigma \leq 1$ the theory predicts the temperature dependence of the microwave conductivity observed in [31], while the theoretical results obtained for $\gamma_\pi/\gamma_\sigma \approx 4-7$ are consistent with the observations in [32, 33].

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Appendix

The quantities $\tilde{\omega}_n$, $\tilde{\Delta}_n$, Δ_n and Γ_{nm} used in [35] are expressed in the notation of the present paper as $\tilde{\omega}_n = \omega Z_n(\omega)$, $\tilde{\Delta}_n = \phi_n(\omega)$, $\Delta_n = \phi_n^0$ and $\Gamma_{nm} = 1/(2\tau_{nm})$ (compare equations (8-11,14,15) in [35] with (5-8) in this work). Note that we reserve the notation $\Delta_n(\omega) = \phi_n(\omega)/Z_n(\omega)$ for the true physical gap function which is experimentally observable, while in [35] it denotes the pairing self-energy resulting from pairing interactions (see equations (14) and (15) in [35]) which is experimentally unobservable for a finite interband impurity scattering rate even in the BCS limit. Then, the functions $u_n(\omega)$ and $v_n(\omega)$ of [35] become $u_n(\omega) \equiv \tilde{\omega}_n/\tilde{\Delta}_n = \omega/\Delta_n(\omega)$ and $v_n(\omega) \equiv \phi_n^0 u_n(\omega)$ and the factor in the square bracket under the integral in the equation (38a) of [35] can be rewritten as ($u_{-n} \equiv u_n(\omega - \nu)$)

$$\begin{aligned} 1 - \frac{v_n v_{-n} + \phi_n^{02}}{\sqrt{v_n^2 - \phi_n^{02}} \sqrt{v_{-n}^2 - \phi_n^{02}}} &= 1 - \frac{u_n u_{-n} + 1}{\sqrt{u_n^2 - 1} \sqrt{u_{-n}^2 - 1}} \\ &= 1 - \frac{\omega(\omega - \nu) + \Delta_n(\omega) \Delta_n(\omega - \nu)}{\sqrt{\omega^2 - \Delta_n^2(\omega)} \sqrt{(\omega - \nu)^2 - \Delta_n^2(\omega - \nu)}} \\ &= 1 - [N_n(\omega) N_n(\omega - \nu) + M_n(\omega) M_n(\omega - \nu)], \end{aligned} \quad (\text{A.1})$$

where in the last step we used the definitions (2) and (3). Moreover, the function γ_n given by the equation (38b) in [35], which determines the remaining factor $1/(\gamma_n + \gamma_{-n})$ in the integrand of (38a) in [35], can be cast in the following form

$$\begin{aligned}
 \gamma_n &= \sqrt{v_n^2 - \phi_n^{02}} + i\Gamma_n + i\Gamma_{nm} \frac{\phi_m^0}{\phi_n^0} \left(\frac{v_n^2 - \phi_n^{02}}{v_m^2 - \phi_m^{02}} \right)^{1/2} \\
 &= \phi_n^0 \sqrt{u_n^2 - 1} + i\Gamma_n + i\Gamma_{nm} \left(\frac{u_n^2 - 1}{u_m^2 - 1} \right)^{1/2} \\
 &= \phi_n^0 \frac{\sqrt{\omega^2 - \Delta_n^2(\omega)}}{\Delta_n(\omega)} + i\Gamma_n + i\Gamma_{nm} \frac{\Delta_m(\omega)}{\Delta_n(\omega)} \frac{\sqrt{\omega^2 - \Delta_n^2(\omega)}}{\sqrt{\omega^2 - \Delta_m^2(\omega)}} \\
 &= \left(\phi_n^0 + i\Gamma_n \frac{\Delta_n(\omega)}{\sqrt{\omega^2 - \Delta_n^2(\omega)}} + i\Gamma_{nm} \frac{\Delta_m(\omega)}{\sqrt{\omega^2 - \Delta_m^2(\omega)}} \right) \frac{\sqrt{\omega^2 - \Delta_n^2(\omega)}}{\Delta_n(\omega)} \quad (\text{A.2}) \\
 &= Z_n(\omega) \sqrt{\omega^2 - \Delta_n^2(\omega)}, \quad (\text{A.3})
 \end{aligned}$$

where in the last step we used (5) and $\Gamma_{nm} = 1/(2\tau_{nm})$, $n, m = \sigma, \pi$, to replace the expression in the bracket in (A.2) with $\phi_n(\omega) = \Delta_n(\omega)Z_n(\omega)$. Thus, γ_n of [35] is precisely equal to the quasiparticle energy $E_n(\omega)$, (4), used in this work. The complex conductivity is obtained from the total response kernel $K_n(0, \nu)$ given by equations (38a) and (38b) in [35] as $iK_n(0, \nu)/\nu$. One should keep in mind that as the cut along the real axis is crossed (i.e. ω is assumed to have infinitesimal negative imaginary part instead of infinitesimal positive imaginary part) $N_n(\omega) \rightarrow -N_n^*(\omega)$, $M_n(\omega) \rightarrow -M_n^*(\omega)$ and $E_n(\omega) \rightarrow -E_n^*(\omega)$ (see section VI of reference [9] in [35] after which the derivation in [35] was patterned).

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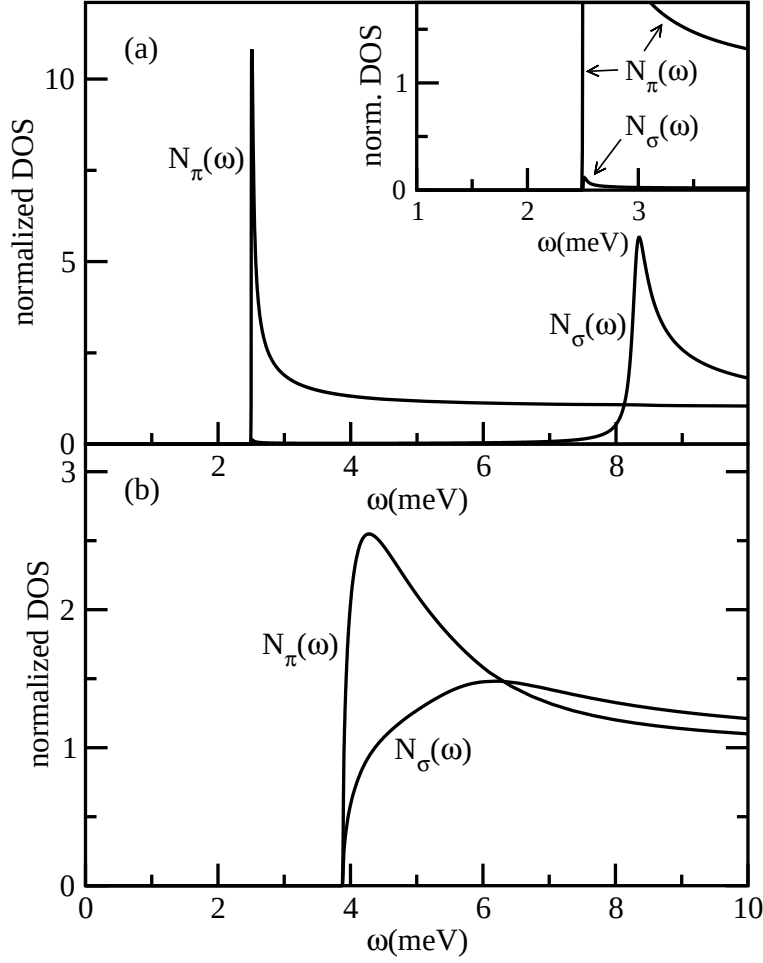


Figure 1. The normalized quasiparticle densities of states $N_{\sigma(\pi)}(\omega) = \text{Re} [\omega / \sqrt{\omega^2 - \Delta_{\sigma(\pi)}^2}(\omega)]$ for MgB_2 at $T=5$ K calculated using the interaction parameters from [24]. (a) The results obtained for the interband impurity scattering rate $1/\tau_{\pi\sigma}=0.1T_{c0}$, where T_{c0} is the transition temperature of the clean compound. The inset shows the details in the densities of states near the common gap. (b) The results obtained for the interband impurity scattering rate $1/\tau_{\pi\sigma}=5T_{c0}$ which is used in the subsequent calculations of the frequency dependent optical conductivity.

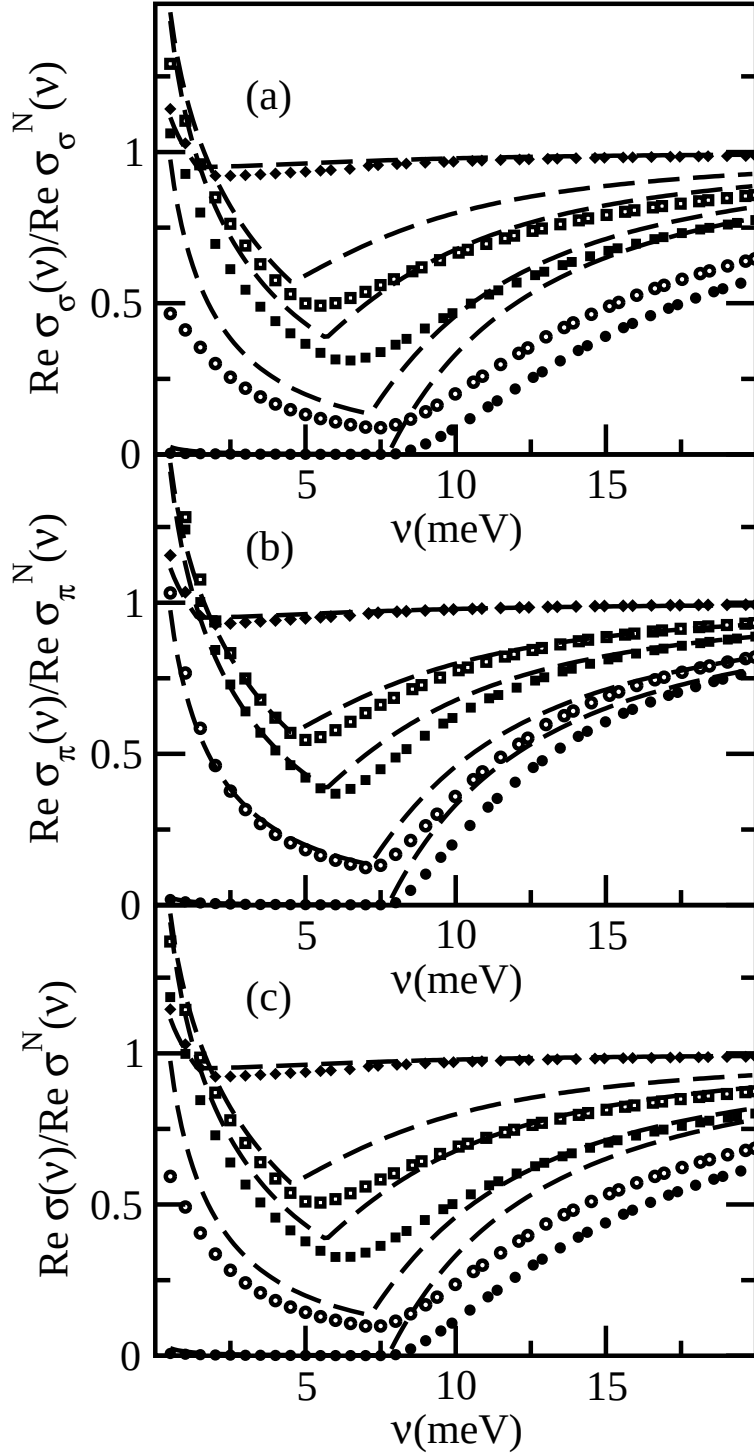


Figure 2. Real part of the conductivity normalized to its normal state value at 40 for $T = 7$ K (filled circles), 19 K (open circles), 26 K (filled squares), 29 K (open squares) and 32.75 K (filled diamonds). The dashed lines are results obtained with Mattis-Bardeen theory at the same temperatures using $\Delta = 3.875$ meV and assuming the BCS temperature dependence of the gap (the temperature increases from the bottom dashed curve to the top one). (a) Results for the σ -band conductivity. (b) Results for the π -band conductivity. (c) Results for the total conductivity $\sigma(\nu) = \sigma_{\sigma}(\nu) + \sigma_{\pi}(\nu)$.

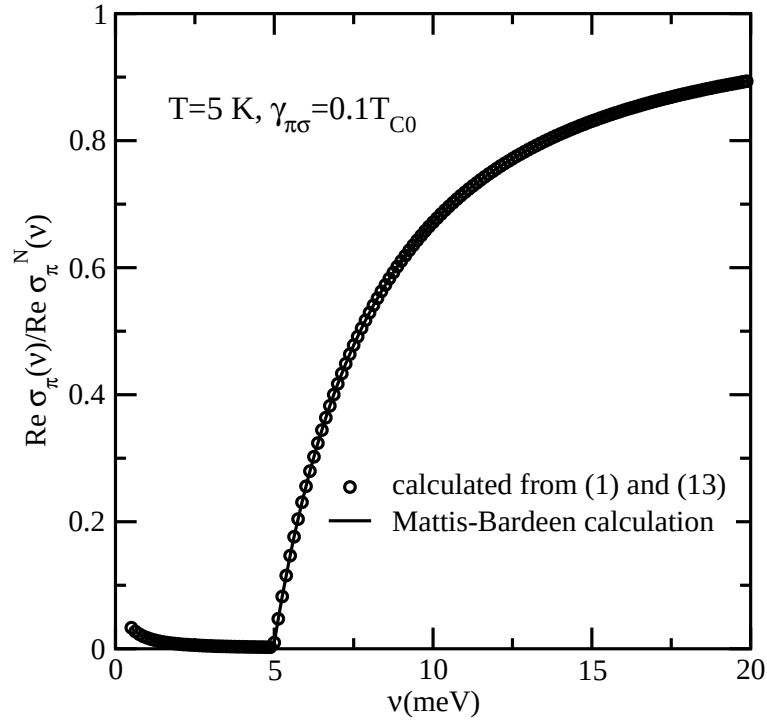


Figure 3. Real part of the π -band conductivity at $T=5$ K normalized to its normal state value at 44 K. The open circles are the results obtained from equations (1) and (13) with the interband scattering rate $\gamma_{\pi\sigma}=0.1T_{C0}$ and with $\gamma_{\pi} = \gamma_{\pi\pi} + \gamma_{\pi\sigma}$ held at 2.6 eV. The solid line gives the results obtained with Mattis-Bardeen theory.

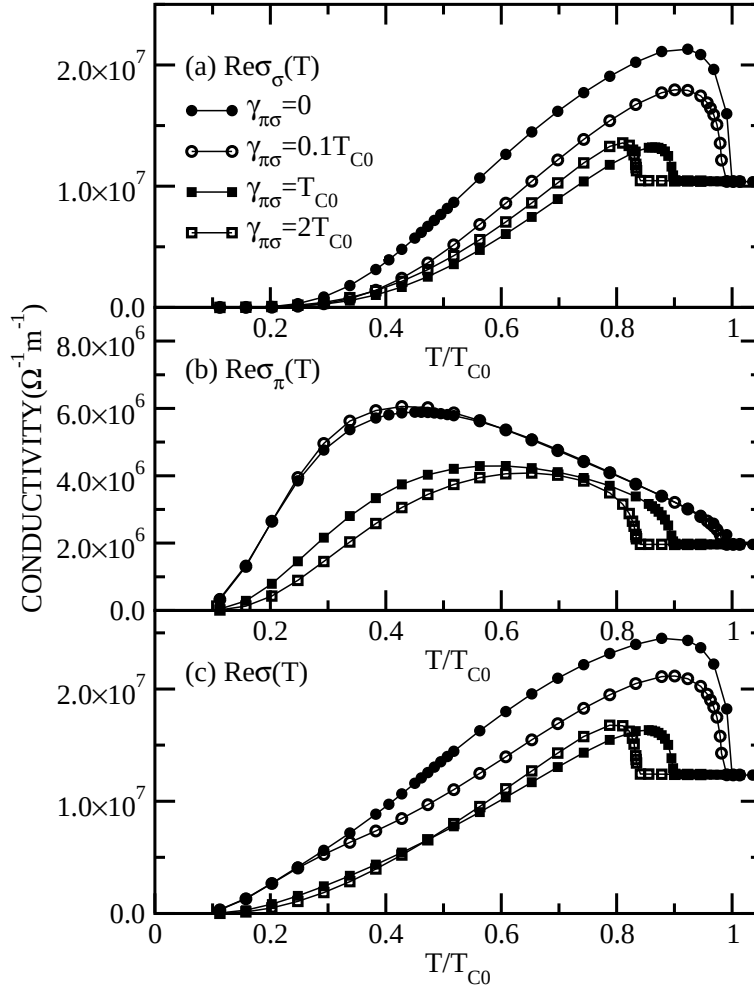


Figure 4. The microwave conductivity at 8.5 GHz as a function of temperature for several different values of the interband scattering rate $\gamma_{\pi\sigma}$ in the units of transition temperature of the clean system T_{c0} , calculated using $\omega_{p\sigma}=4.14$ eV, $\omega_{p\pi}=4.72$ eV, $\gamma_{\pi}/\gamma_{\sigma}=7$ [1] and $\gamma_{\pi}=152.6$ meV (see the text). (a) σ -band contribution $\text{Re}\sigma_{\sigma}(T)$ to the microwave conductivity. Different curves correspond to different values of $\gamma_{\pi\sigma}$ as indicated in the legend. (b) π -band contribution $\text{Re}\sigma_{\pi}(T)$ to the microwave conductivity. The identification of various curves is the same as in (a). (c) The real part of the total microwave conductivity $\text{Re}\sigma(T) = \text{Re}\sigma_{\sigma}(T) + \text{Re}\sigma_{\pi}(T)$. The meaning of different symbols is explained by the legend in (a).

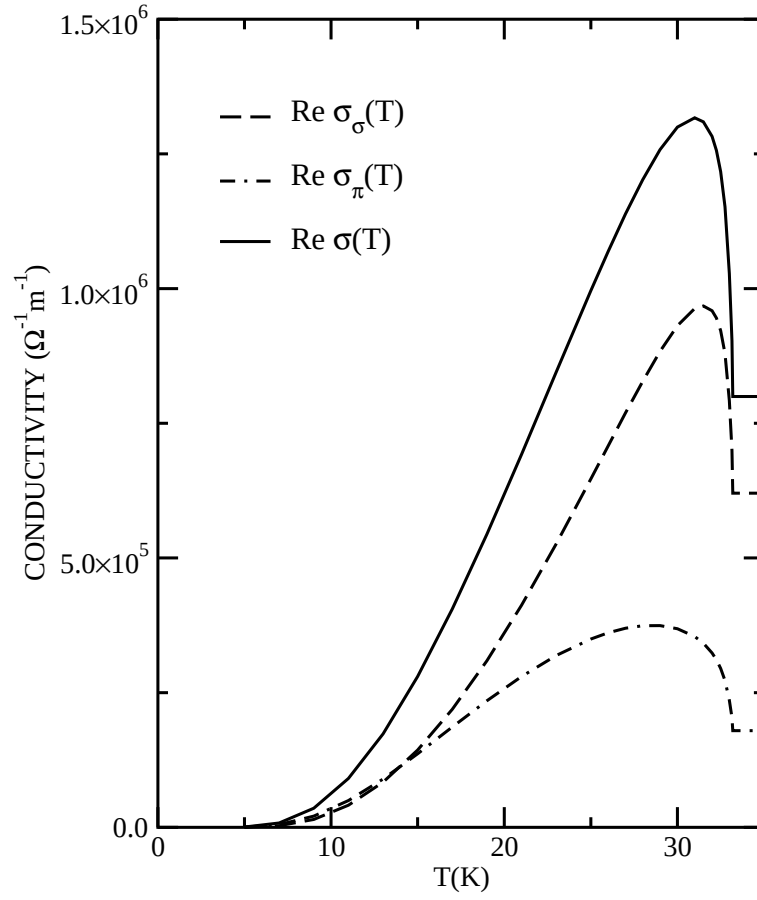


Figure 5. Contributions of different bands and the total microwave conductivity at 8.5 GHz, $\text{Re } \sigma(T) = \text{Re } \sigma_{\sigma}(T) + \text{Re } \sigma_{\pi}(T)$, calculated for the same parameters used to obtain the infrared conductivities in figure 2: $\omega_{p\sigma}=4.14$ eV, $\omega_{p\pi}=5.89$ eV, $\gamma_{\pi}/\gamma_{\sigma}=7$, $\gamma_{\pi}=2.6$ eV and $\gamma_{\pi\sigma}=5T_{c0}$. The corresponding quasiparticle densities of states at a low temperature are given in figure 1b.

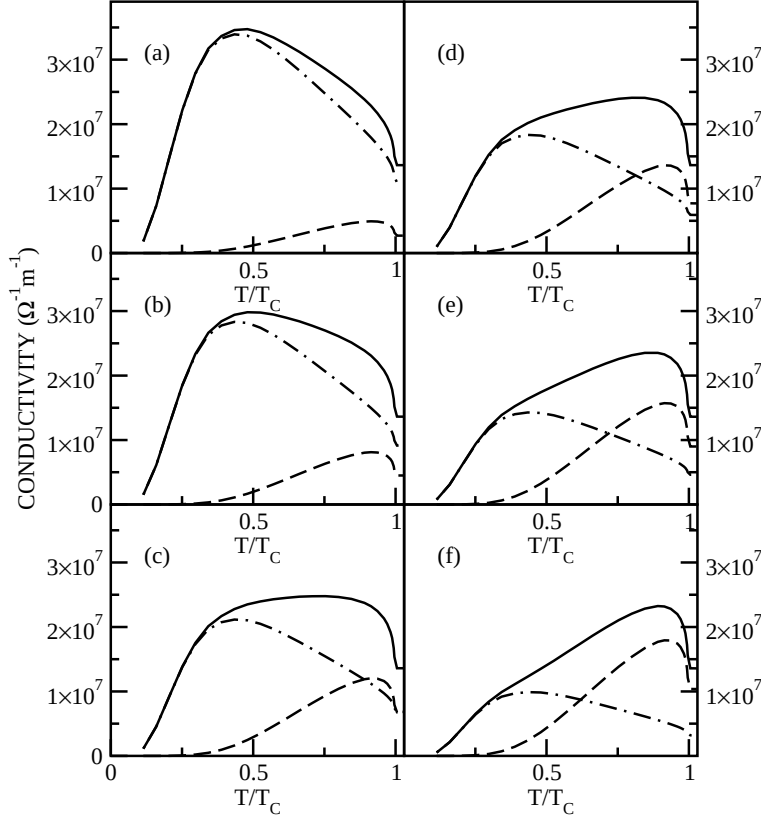


Figure 6. Microwave conductivities for a fixed interband impurity scattering rate $\gamma_{\pi\sigma}=0.1T_{c0}$ for different values of the ratio $\gamma_{\pi}/\gamma_{\sigma}$ with γ_{π} fitted to the measured microwave conductivity at T_c of $1.37\times 10^7/\Omega\text{m}$ [31] with $\omega_{p\sigma}=4.14$ eV, $\omega_{p\pi}=5.89$ eV. The contribution of the σ -band to the microwave conductivity is given by the dashed line, while that of the π -band is given by the dash-dotted line. The total microwave conductivity is represented by the solid line. (a) $\gamma_{\pi}/\gamma_{\sigma}=0.5$. (b) $\gamma_{\pi}/\gamma_{\sigma}=1$. (c) $\gamma_{\pi}/\gamma_{\sigma}=2$. (d) $\gamma_{\pi}/\gamma_{\sigma}=2.67$. (e) $\gamma_{\pi}/\gamma_{\sigma}=4$. (f) $\gamma_{\pi}/\gamma_{\sigma}=6.67$.